



# 5SDF 06T3004

Old part no. DM 827C-620-30

## Fast Recovery Diode

### Properties

- § Optimized recovery characteristics
- § Industry standard housing

### Applications

- § suited for GTO applications
- § Snubber diode
- § Freewheeling diode

### Key Parameters

$V_{RRM}$	=	3 000	V
$I_{FAVm}$	=	615	A
$I_{FSM}$	=	10 000	A
$V_{TO}$	=	1.196	V
$r_T$	=	0.461	m $\Omega$

### Types

	$V_{RRM}$
5SDF 06T3004	3 000 V
5SDF 06T2504	2 500 V
Conditions: $T_j = -40 \div 125$ °C, half sine waveform, $f = 50$ Hz	

### Mechanical Data

$F_m$	Mounting force	10 ± 2 kN
$m$	Weight	0.20 kg
$D_s$	Surface creepage distance	20 mm
$D_a$	Air strike distance	14 mm

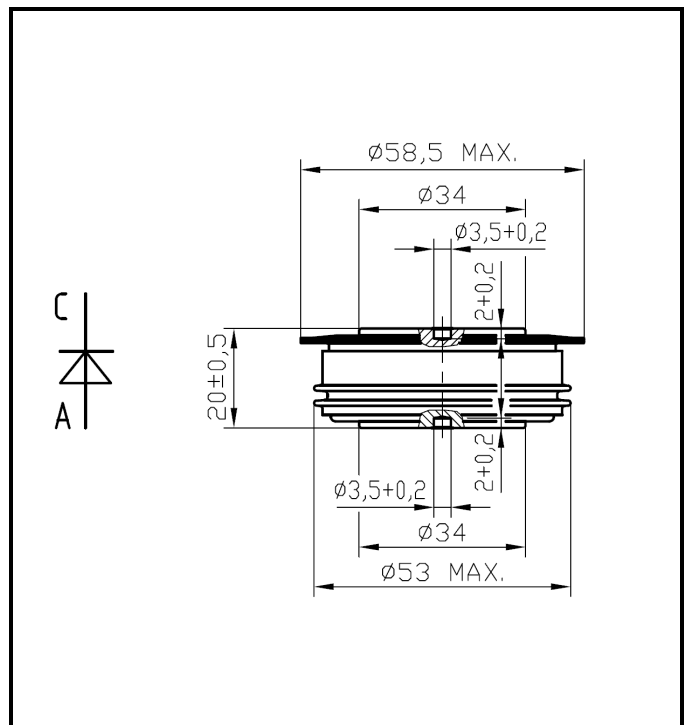


Fig. 1 Case



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<b>Maximum Ratings</b>			<b>Maximum Limits</b>	<b>Unit</b>
$V_{RRM}$	<b>Repetitive peak reverse voltage</b> $T_j = -40 \div 125 \text{ }^\circ\text{C}$	<b>5SDF 06T3004</b> <b>5SDF 06T2504</b>	<b>3 000</b> <b>2 500</b>	<b>V</b>
$I_{FAVm}$	<b>Average forward current</b> $T_c = 85 \text{ }^\circ\text{C}$		<b>615</b>	<b>A</b>
$I_{FRMS}$	<b>RMS forward current</b> $T_c = 85 \text{ }^\circ\text{C}$		<b>966</b>	<b>A</b>
$I_{RRM}$	<b>Repetitive reverse current</b> $V_R = V_{RRM}$		<b>50</b>	<b>mA</b>
$I_{FSM}$	<b>Non repetitive peak surge current</b> $V_R = 0 \text{ V, half sine pulse}$	$t_p = 8.3 \text{ ms}$	<b>10 700</b>	<b>A</b>
		$t_p = 10 \text{ ms}$	<b>10 000</b>	<b>A</b>
$\int i^2 t$	<b>Limiting load integral</b> $V_R = 0 \text{ V, half sine pulse}$	$t_p = 8.3 \text{ ms}$	<b>474 000</b>	<b>A<sup>2</sup>s</b>
		$t_p = 10 \text{ ms}$	<b>500 000</b>	<b>A<sup>2</sup>s</b>
$T_{jmin} - T_{jmax}$	<b>Operating temperature range</b>		<b>-40 <math>\div</math> 125</b>	<b>°C</b>
$T_{STG}$	<b>Storage temperature range</b>		<b>-40 <math>\div</math> 125</b>	<b>°C</b>

Unless otherwise specified  $T_j = 125 \text{ }^\circ\text{C}$

Characteristics		Value			Unit
		min	typ	max	
$V_{T0}$	Threshold voltage			1.196	V
$r_T$	Forward slope resistance $I_{F1} = 974 \text{ A}, I_{F2} = 2\,922 \text{ A}$			0.461	mW
$V_{FM}$	Maximum forward voltage $I_{FM} = 1\,000 \text{ A}$			1.660	V
$Q_{rr}$	Recovered charge $V_R = 100 \text{ V}, I_{FM} = 1000 \text{ A}, di/dt = -80 \text{ A}/\mu\text{s}$		260	400	$\mu\text{C}$
$I_{rrM}$	Reverse recovery maximum current <i>the same conditions as at <math>Q_{rr}</math></i>		120	200	A
$t_{rr}$	Reverse recovery time <i>the same conditions as at <math>Q_{rr}</math></i>			4.0	$\mu\text{s}$
<b>S</b>	Soft factor, $S = t_s / t_f$ $I_{FM} = 1\,000 \text{ A}, di_f/dt = -200 \text{ A}/\mu\text{s}, V_R = 400 \text{ V}$		2.0		-
$I_{rrM}$	Reverse recovery maximum current <i>the same conditions as at S</i>			400	A
$V_{rrM}$	Reverse recovery maximum voltage <i>the same conditions as at S</i>			1 100	V

Unless otherwise specified  $T_j = 125 \text{ }^\circ\text{C}$

Thermal Parameters			Value	Unit
$R_{thjc}$	Thermal resistance junction to case	double side cooling	32	K/kW
		cathode side cooling	50	
		anode side cooling	88	
$R_{thch}$	Thermal resistance case to heatsink	double side cooling	8	K/kW
		single side cooling	16	

Transient Thermal Impedance														
<b>Analytical function for transient thermal impedance</b>  $Z_{thjc} = \sum_{i=1}^5 R_i (1 - \exp(-t / \tau_i))$	$i$	1	2	3	4	5								
	$t_i$ (s)	0.7033	0.2185	0.0588	0.0042	0.0006								
	$R_i$ (K/kW)	11.56	10.08	7.84	2.38	0.13								
Conditions: $F_m = 10 \pm 2$ kN, Double side cooled  <b>Correction for periodic waveforms</b>	<table border="1"> <tr> <td>180° sine:</td> <td>2.3 K/kW</td> </tr> <tr> <td>180° rectangular:</td> <td>3.1 K/kW</td> </tr> <tr> <td>120° rectangular:</td> <td>5.1 K/kW</td> </tr> <tr> <td>60° rectangular:</td> <td>8.7 K/kW</td> </tr> </table>	180° sine:	2.3 K/kW	180° rectangular:	3.1 K/kW	120° rectangular:	5.1 K/kW	60° rectangular:	8.7 K/kW					
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120° rectangular:	5.1 K/kW													
60° rectangular:	8.7 K/kW													
Fig. 2 Dependence transient thermal impedance junction to case on square pulse														

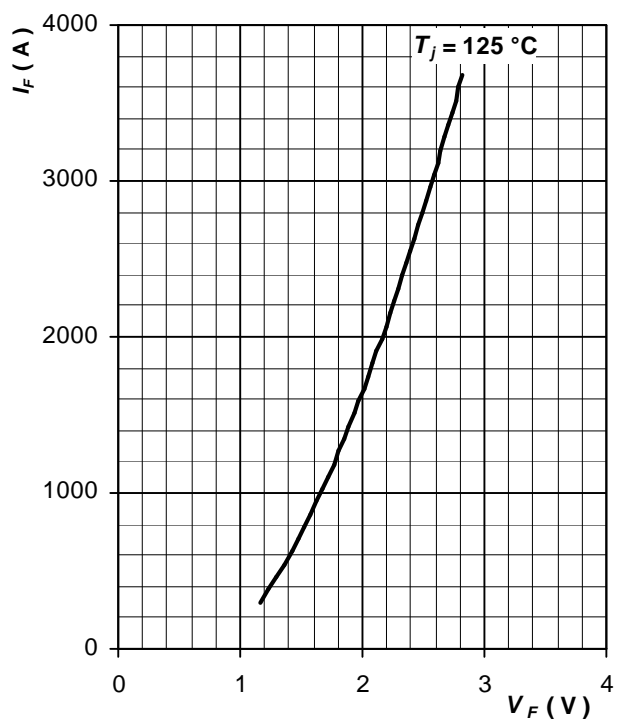
**Forward Characteristics**

Fig. 3 Maximum forward voltage drop characteristics

**Surge Characteristics**

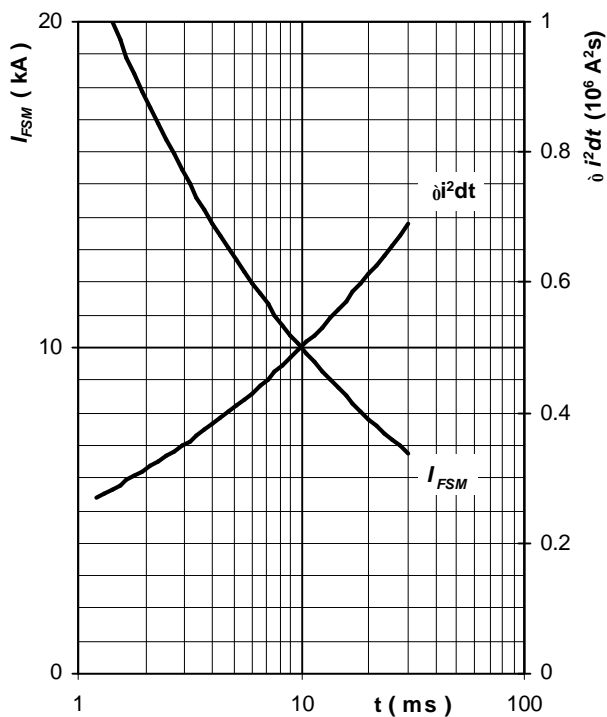


Fig. 4 Surge forward current vs. pulse length, half sine wave, single pulse,  $V_R = 0$  V,  $T_j = T_{jmax}$

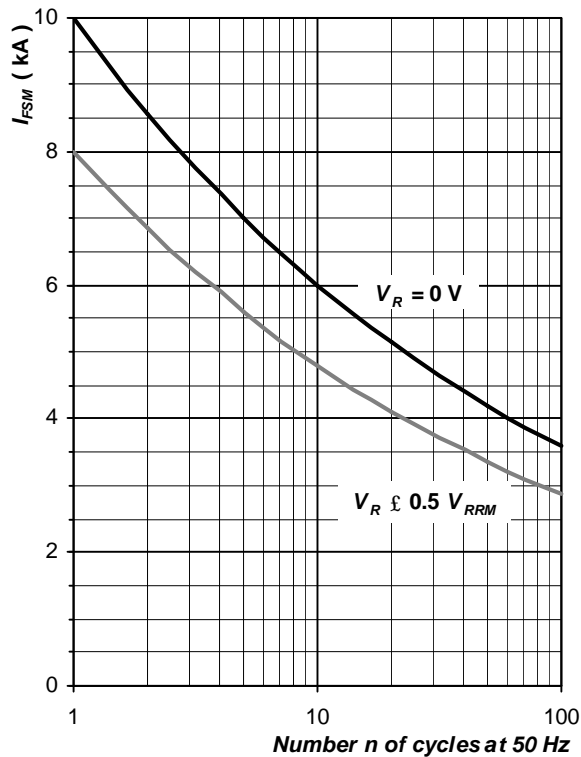


Fig. 5 Surge forward current vs. number of pulses, half sine wave,  $T_j = T_{jmax}$

**Power Loss and Maximum Case Temperature Characteristics**

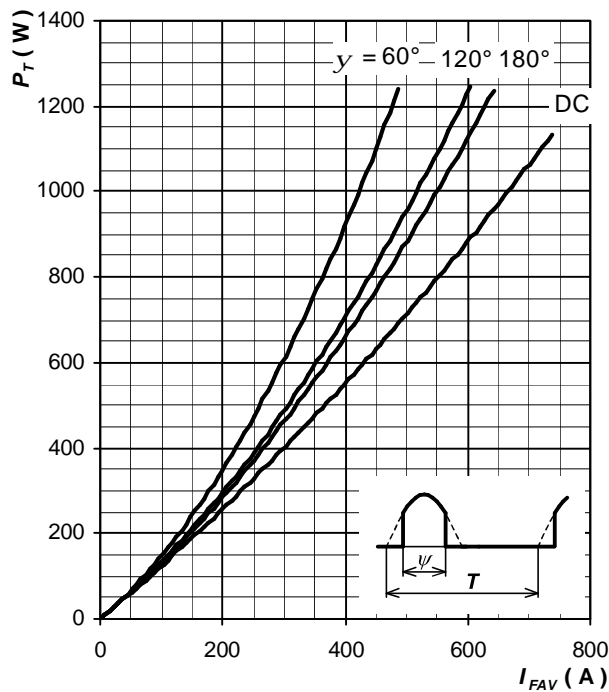


Fig. 6 Forward power loss vs. average forward current, sine waveform,  $f = 50$  Hz,  $T = 1/f$

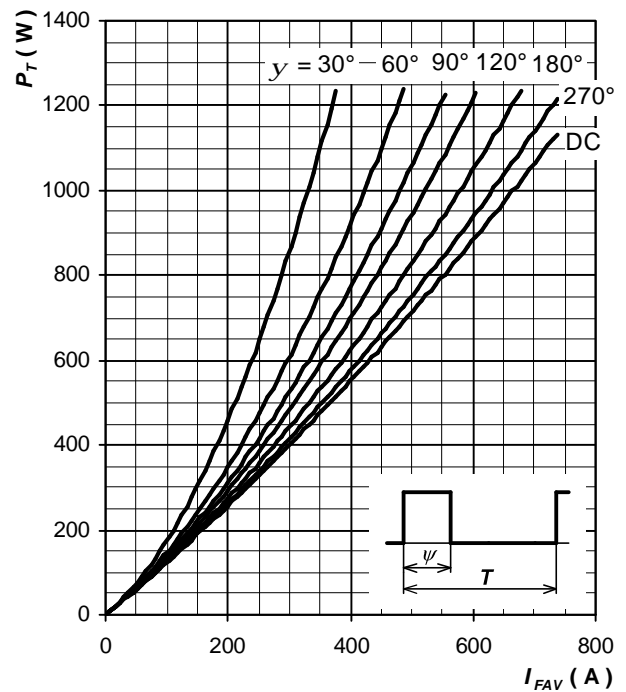


Fig. 7 Forward power loss vs. average forward current, square waveform,  $f = 50$  Hz,  $T = 1/f$

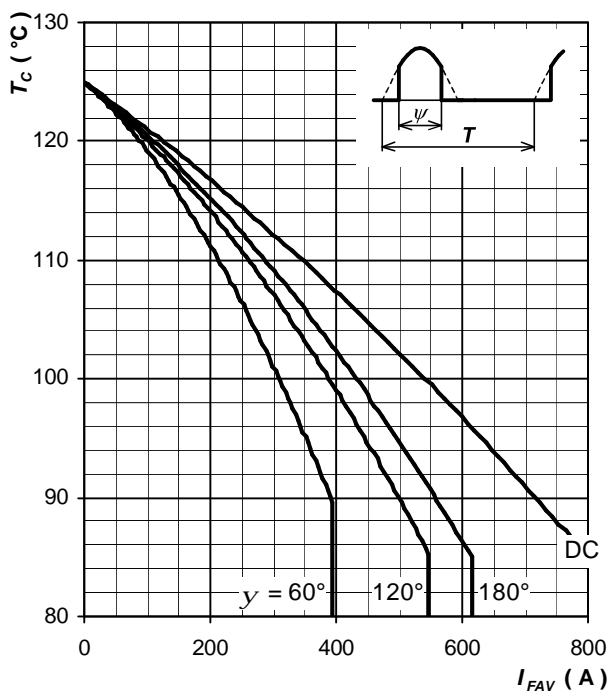


Fig. 8 Max. case temperature vs. aver. forward current, sine waveform,  $f = 50$  Hz,  $T = 1/f$

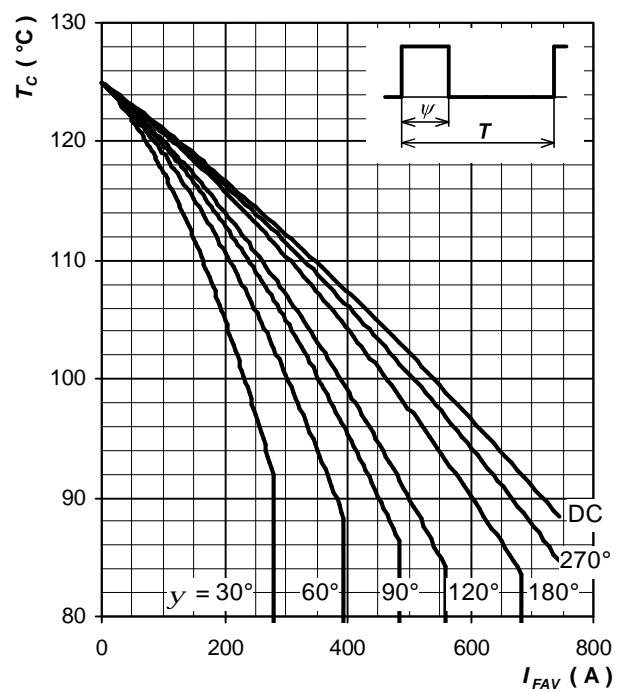


Fig. 9 Max. case temperature vs. aver. forward current, square waveform,  $f = 50$  Hz,  $T = 1/f$

Note 2: Figures number 6 , 9 have been calculated without considering any forward and reverse recovery losses. They are valid for  $f = 50$  or  $60$  Hz operation.

**Forward Recovery Characteristics**

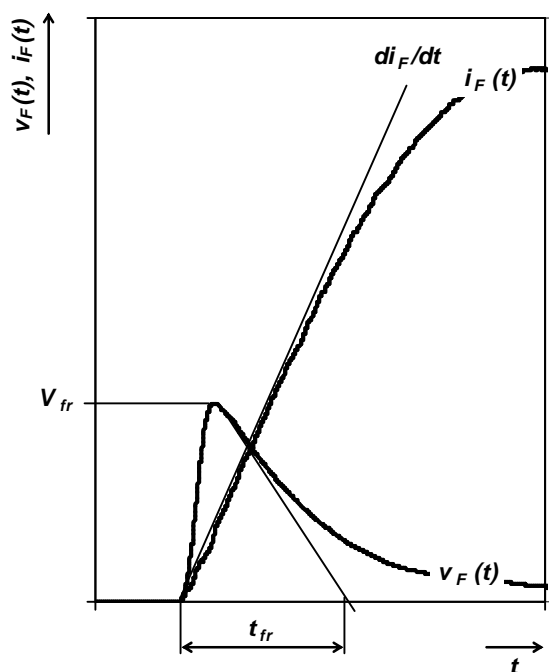


Fig. 10 Typical forward recovery voltage waveform when the diode is turned on with high  $di_F/dt$

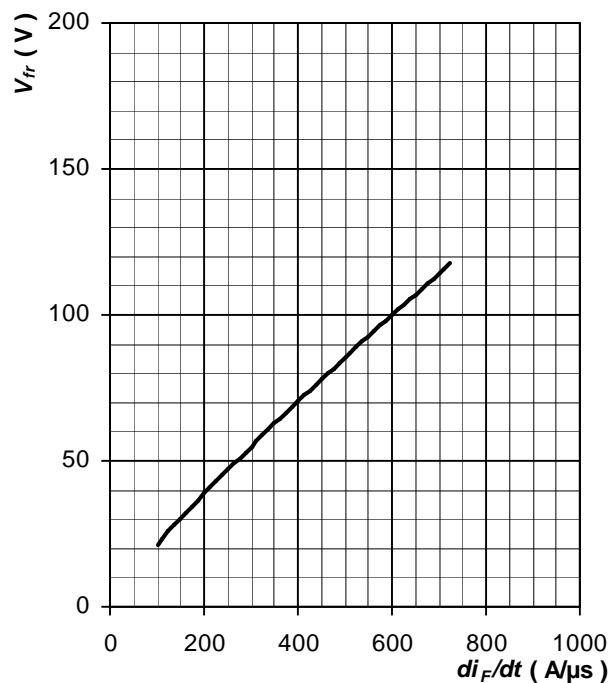


Fig. 11 Max. forward recovery voltage vs. rate of rise of forward current, trapezoid pulse,  $T_j = T_{jmax}$ ,  $t_{fr} \leq 10 \mu s$



**Reverse Recovery Characteristics**

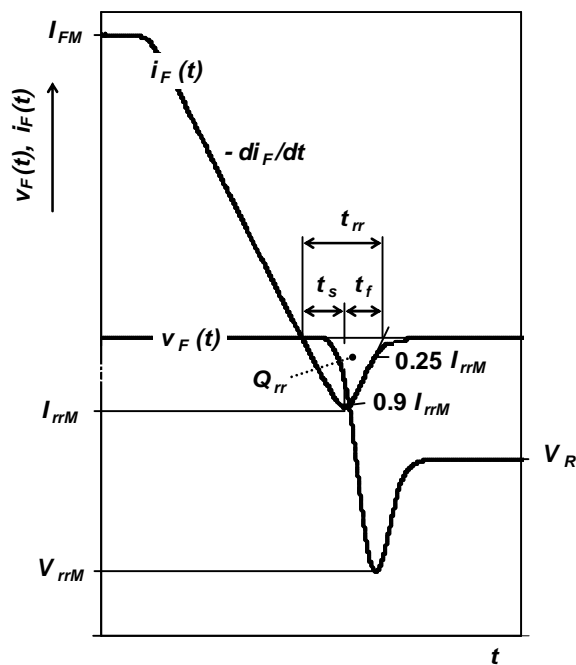


Fig. 12 Typical waveforms and definition of symbols at reverse recovery of a diode, inductive switching without RC snubber

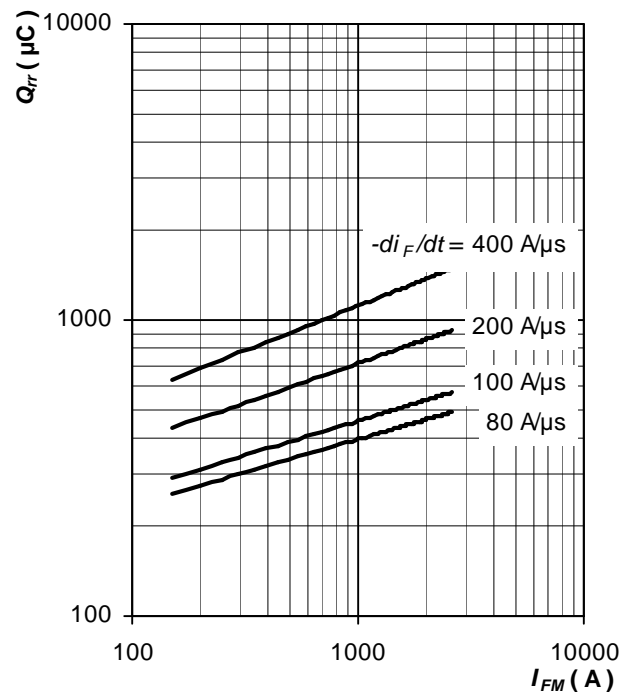


Fig. 13 Max. recovered charge vs. forward current, trapezoid pulse,  $T_j = T_{jmax}$

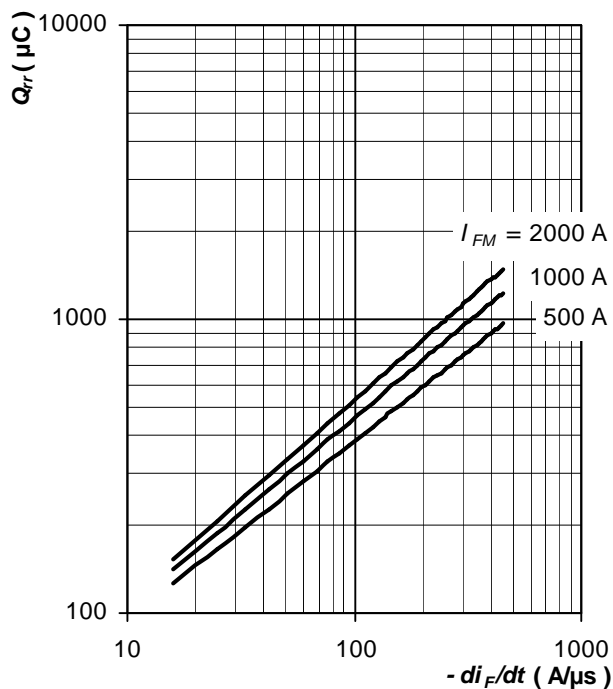


Fig. 14 Max. recovered charge vs. rate of fall of forward current, trapezoid pulse,  $T_j = T_{jmax}$

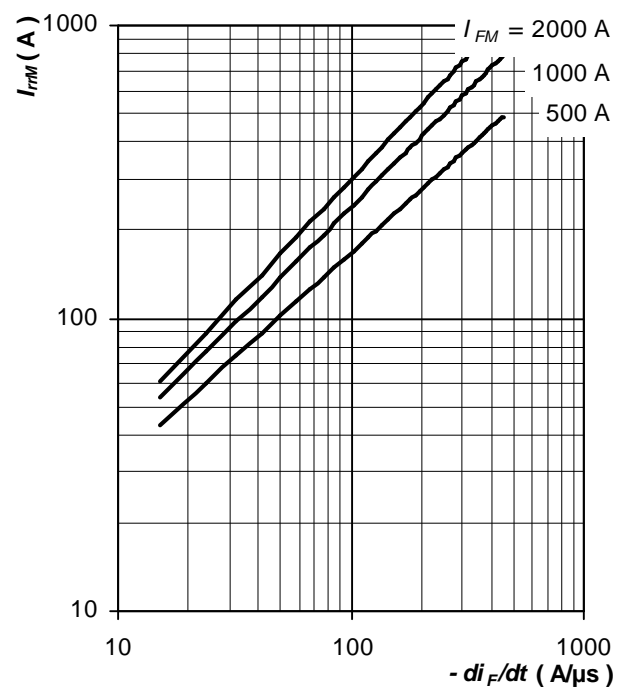


Fig. 15 Max. reverse recovery current vs. rate of fall of forward current, trapezoid pulse,  $T_j = T_{jmax}$